Qiangfei Xia

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 100
 9,563
 44
 97

 papers
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 g-index

 106
 12,048
 12.8
 6.6

 ext. papers
 ext. citations
 avg, IF
 L-index

#	Paper	IF	Citations
100	Memristors with diffusive dynamics as synaptic emulators for neuromorphic computing. <i>Nature Materials</i> , 2017 , 16, 101-108	27	1201
99	Memristive crossbar arrays for brain-inspired computing. <i>Nature Materials</i> , 2019 , 18, 309-323	27	582
98	Analogue signal and image processing with large memristor crossbars. <i>Nature Electronics</i> , 2018 , 1, 52-5	928.4	550
97	Fully memristive neural networks for pattern classification with unsupervised learning. <i>Nature Electronics</i> , 2018 , 1, 137-145	28.4	511
96	Memristor-CMOS hybrid integrated circuits for reconfigurable logic. <i>Nano Letters</i> , 2009 , 9, 3640-5	11.5	507
95	Black Phosphorus Mid-Infrared Photodetectors with High Gain. <i>Nano Letters</i> , 2016 , 16, 4648-55	11.5	476
94	Efficient and self-adaptive in-situ learning in multilayer memristor neural networks. <i>Nature Communications</i> , 2018 , 9, 2385	17.4	371
93	Memristor-Based Analog Computation and Neural Network Classification with a Dot Product Engine. <i>Advanced Materials</i> , 2018 , 30, 1705914	24	339
92	Resistive switching materials for information processing. <i>Nature Reviews Materials</i> , 2020 , 5, 173-195	73.3	318
91	Anatomy of Ag/Hafnia-Based Selectors with 10 Nonlinearity. <i>Advanced Materials</i> , 2017 , 29, 1604457	24	245
90	Memristor crossbar arrays with 6-nm half-pitch and 2-nm critical dimension. <i>Nature Nanotechnology</i> , 2019 , 14, 35-39	28.7	231
89	Efficient electrical control of thin-film black phosphorus bandgap. <i>Nature Communications</i> , 2017 , 8, 144	74 7.4	183
88	An artificial nociceptor based on a diffusive memristor. <i>Nature Communications</i> , 2018 , 9, 417	17.4	183
87	Review of memristor devices in neuromorphic computing: materials sciences and device challenges. Journal Physics D: Applied Physics, 2018, 51, 503002	3	183
86	Emerging Memory Devices for Neuromorphic Computing. Advanced Materials Technologies, 2019, 4, 180	0 %5 89	181
85	A novel true random number generator based on a stochastic diffusive memristor. <i>Nature Communications</i> , 2017 , 8, 882	17.4	180
84	Long short-term memory networks in memristor crossbar arrays. <i>Nature Machine Intelligence</i> , 2019 , 1, 49-57	22.5	176

(2019-2018)

83	Threshold Switching of Ag or Cu in Dielectrics: Materials, Mechanism, and Applications. <i>Advanced Functional Materials</i> , 2018 , 28, 1704862	15.6	168
82	Reinforcement learning with analogue memristor arrays. <i>Nature Electronics</i> , 2019 , 2, 115-124	28.4	166
81	Understanding memristive switching via in situ characterization and device modeling. <i>Nature Communications</i> , 2019 , 10, 3453	17.4	138
80	Capacitive neural network with neuro-transistors. <i>Nature Communications</i> , 2018 , 9, 3208	17.4	132
79	Sub-10 nm Ta Channel Responsible for Superior Performance of a HfO2 Memristor. <i>Scientific Reports</i> , 2016 , 6, 28525	4.9	128
78	Three-dimensional crossbar arrays of self-rectifying Si/SiO/Si memristors. <i>Nature Communications</i> , 2017 , 8, 15666	17.4	115
77	Three-dimensional memristor circuits as complex neural networks. <i>Nature Electronics</i> , 2020 , 3, 225-232	28.4	112
76	An artificial spiking afferent nerve based on Mott memristors for neurorobotics. <i>Nature Communications</i> , 2020 , 11, 51	17.4	105
75	Silicon Oxide (SiO): A Promising Material for Resistance Switching?. <i>Advanced Materials</i> , 2018 , 30, e180	14,87	105
74	Diffusion of adhesion layer metals controls nanoscale memristive switching. <i>Advanced Materials</i> , 2010 , 22, 4034-8	24	95
73	In situ training of feed-forward and recurrent convolutional memristor networks. <i>Nature Machine Intelligence</i> , 2019 , 1, 434-442	22.5	93
72	Synthetic Biological Protein Nanowires with High Conductivity. <i>Small</i> , 2016 , 12, 4481-5	11	87
71	Self-aligned memristor cross-point arrays fabricated with one nanoimprint lithography step. <i>Nano Letters</i> , 2010 , 10, 2909-14	11.5	85
70	Power-efficient combinatorial optimization using intrinsic noise in memristor Hopfield neural networks. <i>Nature Electronics</i> , 2020 , 3, 409-418	28.4	79
69	Sub-10 nm self-enclosed self-limited nanofluidic channel arrays. <i>Nano Letters</i> , 2008 , 8, 3830-3	11.5	79
68	Nanoscale memristive radiofrequency switches. <i>Nature Communications</i> , 2015 , 6, 7519	17.4	76
67	A Dynamically Reconfigurable Ambipolar Black Phosphorus Memory Device. ACS Nano, 2016 , 10, 10428	- 16 4/35	72

65	Two- and Three-Terminal Resistive Switches: Nanometer-Scale Memristors and Memistors. <i>Advanced Functional Materials</i> , 2011 , 21, 2660-2665	15.6	64
64	Improved nanofabrication through guided transient liquefaction. <i>Nature Nanotechnology</i> , 2008 , 3, 295-	3 08 .7	63
63	Ultrafast patterning of nanostructures in polymers using laser assisted nanoimprint lithography. <i>Applied Physics Letters</i> , 2003 , 83, 4417-4419	3.4	57
62	Truly Electroforming-Free and Low-Energy Memristors with Preconditioned Conductive Tunneling Paths. <i>Advanced Functional Materials</i> , 2017 , 27, 1702010	15.6	56
61	Cross point arrays of 8 nm 🛭 nm memristive devices fabricated with nanoimprint lithography. Journal of Vacuum Science and Technology B:Nanotechnology and Microelectronics, 2013, 31, 06FA02	1.3	56
60	A memristor-based nonvolatile latch circuit. <i>Nanotechnology</i> , 2010 , 21, 235203	3.4	56
59	Artificial Neural Network (ANN) to Spiking Neural Network (SNN) Converters Based on Diffusive Memristors. <i>Advanced Electronic Materials</i> , 2019 , 5, 1900060	6.4	55
58	Nucleation limited switching (NLS) model for HfO2-based metal-ferroelectric-metal (MFM) capacitors: Switching kinetics and retention characteristics. <i>Applied Physics Letters</i> , 2018 , 112, 262903	3.4	46
57	Roadmap on emerging hardware and technology for machine learning. <i>Nanotechnology</i> , 2021 , 32, 0120	103.4	45
56	Hybrid CMOS/memristor circuits 2010 ,		39
56 55	Hybrid CMOS/memristor circuits 2010 , Nanoscale diffusive memristor crossbars as physical unclonable functions. <i>Nanoscale</i> , 2018 , 10, 2721-27	72 ₇ 67	39 36
		1 2/6 7 16.7	36
55	Nanoscale diffusive memristor crossbars as physical unclonable functions. <i>Nanoscale</i> , 2018 , 10, 2721-27	, ,	36
55 54	Nanoscale diffusive memristor crossbars as physical unclonable functions. <i>Nanoscale</i> , 2018 , 10, 2721-27. Standards for the Characterization of Endurance in Resistive Switching Devices. <i>ACS Nano</i> , 2021 , Ferroelectric transistors with monolayer molybdenum disulfide and ultra-thin aluminum-doped	16.7	36 36
555453	Nanoscale diffusive memristor crossbars as physical unclonable functions. <i>Nanoscale</i> , 2018 , 10, 2721-27. Standards for the Characterization of Endurance in Resistive Switching Devices. <i>ACS Nano</i> , 2021 , Ferroelectric transistors with monolayer molybdenum disulfide and ultra-thin aluminum-doped hafnium oxide. <i>Applied Physics Letters</i> , 2017 , 111, 013103 Electrochemical metallization switching with a platinum group metal in different oxides. <i>Nanoscale</i> ,	16.7 3.4 7.7	36 36 33
55545352	Nanoscale diffusive memristor crossbars as physical unclonable functions. <i>Nanoscale</i> , 2018 , 10, 2721-27. Standards for the Characterization of Endurance in Resistive Switching Devices. <i>ACS Nano</i> , 2021 , Ferroelectric transistors with monolayer molybdenum disulfide and ultra-thin aluminum-doped hafnium oxide. <i>Applied Physics Letters</i> , 2017 , 111, 013103 Electrochemical metallization switching with a platinum group metal in different oxides. <i>Nanoscale</i> , 2016 , 8, 14023-30	16.7 3.4 7.7	3636333332
5554535251	Nanoscale diffusive memristor crossbars as physical unclonable functions. <i>Nanoscale</i> , 2018 , 10, 2721-27. Standards for the Characterization of Endurance in Resistive Switching Devices. <i>ACS Nano</i> , 2021 , Ferroelectric transistors with monolayer molybdenum disulfide and ultra-thin aluminum-doped hafnium oxide. <i>Applied Physics Letters</i> , 2017 , 111, 013103 Electrochemical metallization switching with a platinum group metal in different oxides. <i>Nanoscale</i> , 2016 , 8, 14023-30 A Low-Current and Analog Memristor with Ru as Mobile Species. <i>Advanced Materials</i> , 2020 , 32, e190459. A provable key destruction scheme based on memristive crossbar arrays. <i>Nature Electronics</i> , 2018 ,	16.7 3.4 7.7	3636333332

(2021-2017)

47	Organic electronics: Battery-like artificial synapses. <i>Nature Materials</i> , 2017 , 16, 396-397	27	24
46	Artificial Neural Network Based on Doped HfO2 Ferroelectric Capacitors With Multilevel Characteristics. <i>IEEE Electron Device Letters</i> , 2019 , 40, 1309-1312	4.4	24
45	An efficient analog Hamming distance comparator realized with a unipolar memristor array: a showcase of physical computing. <i>Scientific Reports</i> , 2017 , 7, 40135	4.9	22
44	3D integration of planar crossbar memristive devices with CMOS substrate. <i>Nanotechnology</i> , 2014 , 25, 405202	3.4	22
43	Impact of geometry on the performance of memristive nanodevices. <i>Nanotechnology</i> , 2011 , 22, 254026	3.4	22
42	A Memristor with Low Switching Current and Voltage for 1S1R Integration and Array Operation. <i>Advanced Electronic Materials</i> , 2020 , 6, 1901411	6.4	21
41	Committee machines-a universal method to deal with non-idealities in memristor-based neural networks. <i>Nature Communications</i> , 2020 , 11, 4273	17.4	20
40	Applications of excimer laser in nanofabrication. <i>Applied Physics A: Materials Science and Processing</i> , 2010 , 98, 9-59	2.6	18
39	Nanoscale resistive switches: devices, fabrication and integration. <i>Applied Physics A: Materials Science and Processing</i> , 2011 , 102, 955-965	2.6	17
38	Effect of voltage polarity and amplitude on electroforming of TiO2 based memristive devices. <i>Nanoscale</i> , 2013 , 5, 3257-61	7.7	16
37	Ultrafast and selective reduction of sidewall roughness in silicon waveguides using self-perfection by liquefaction. <i>Nanotechnology</i> , 2009 , 20, 345302	3.4	16
36	Fabrication of a 60-nm-diameter perfectly round metal-dot array over a large area on a plastic substrate using nanoimprint lithography and self-perfection by liquefaction. <i>Small</i> , 2010 , 6, 1242-7	11	14
35	Fabrication of sub-25hm diameter pillar nanoimprint molds with smooth sidewalls using self-perfection by liquefaction and reactive ion etching. <i>Nanotechnology</i> , 2008 , 19, 455301	3.4	14
34	Single- and bi-layer memristive devices with tunable properties using TiOx switching layers deposited by reactive sputtering. <i>Applied Physics Letters</i> , 2014 , 104, 153505	3.4	12
33	Improvement of resistive switching uniformity for TiO2-based memristive devices by introducing a thin HfO2 layer. <i>Journal of Vacuum Science and Technology B:Nanotechnology and Microelectronics</i> , 2013 , 31, 06FA04	1.3	12
32	In-Memory Computing with Memristor Arrays 2018,		12
31	Pulse-Width Modulation based Dot-Product Engine for Neuromorphic Computing System using Memristor Crossbar Array 2018 ,		10
30	A fully hardware-based memristive multilayer neural network. <i>Science Advances</i> , 2021 , 7, eabj4801	14.3	10

29	Fabrication of sub-10 nm metal nanowire arrays with sub-1 nm critical dimension control. <i>Nanotechnology</i> , 2016 , 27, 464004	3.4	10
28	Experimental Demonstration of Conversion-Based SNNs with 1T1R Mott Neurons for Neuromorphic Inference 2019 ,		10
27	Artificial neural networks based on memristive devices. <i>Science China Information Sciences</i> , 2018 , 61, 1	3.4	9
26	Nanoimprint lithography 20 years on. <i>Nanotechnology</i> , 2015 , 26, 182501	3.4	8
25	Cyclical sensing integrate-and-fire circuit for memristor array based neuromorphic computing 2016,		8
24	On the integration of memristors with CMOS using nanoimprint lithography 2009,		8
23	Timing Selector: Using Transient Switching Dynamics to Solve the Sneak Path Issue of Crossbar Arrays. <i>Small Science</i> ,2100072		8
22	Nanoimprint lithography enables memristor crossbars and hybrid circuits. <i>Applied Physics A: Materials Science and Processing</i> , 2015 , 121, 467-479	2.6	7
21	Threshold Switching: Threshold Switching of Ag or Cu in Dielectrics: Materials, Mechanism, and Applications (Adv. Funct. Mater. 6/2018). <i>Advanced Functional Materials</i> , 2018 , 28, 1870036	15.6	7
20	Mold cleaning with polydimethylsiloxane for nanoimprint lithography. <i>Nanotechnology</i> , 2013 , 24, 32530	3 .4	7
19	Three-Dimensional Crossbar Arrays of Self-rectifying Si/SiO2/Si Memristors 2019 , 791-813		7
18	Large Memristor Crossbars for Analog Computing 2018 ,		6
17	A Dynamical Compact Model of Diffusive and Drift Memristors for Neuromorphic Computing. <i>Advanced Electronic Materials</i> ,2100696	6.4	6
16	Memristors as radiofrequency switches 2016 ,		6
15	Tutorial: Fabrication and three-dimensional integration of nanoscale memristive devices and arrays. <i>Journal of Applied Physics</i> , 2018 , 124, 152001	2.5	5
14	Learning with Resistive Switching Neural Networks 2019 ,		4
13	Memristor Device Engineering and CMOS Integration for Reconfigurable Logic Applications 2014 , 327-3	51	3
12	Scalable 3D Ta:SiOx Memristive Devices. <i>Advanced Electronic Materials</i> , 2019 , 5, 1800958	6.4	2

LIST OF PUBLICATIONS

11	Memristive nanodevices: CMOS compatibility and novel applications 2016 ,		2
10	Unconventional computing with diffusive memristors 2018,		2
9	Device engineering and CMOS integration of nanoscale memristors 2014,		2
8	Engineering Tunneling Selector to Achieve High Non-linearity for 1S1R Integration. <i>Frontiers in Nanotechnology</i> , 2021 , 3,	5.5	2
7	Memristor-CMOS Analog Coprocessor for Acceleration of High-Performance Computing Applications. <i>ACM Journal on Emerging Technologies in Computing Systems</i> , 2018 , 14, 1-30	1.7	2
6	Nanoscale memristors: Devices engineering, CMOS integration and novel applications 2015,		1
5	The secret order of disorder. <i>Nature Materials</i> , 2021 ,	27	1
4	Built-in selectors self-assembled into memristors 2016 ,		1
3	Correction: Electrochemical metallization switching with a platinum group metal in different oxides. <i>Nanoscale</i> , 2016 , 8, 11766	7.7	1
2	Three-dimensional hybrid circuits: the future of neuromorphic computing hardware. <i>Nano Express</i> , 2021 , 2, 031003	2	

Ta/HfO2-based Memristor and Crossbar Arrays for In-Memory Computing **2022**, 167-188